



flowPACK E2

1200 V / 50 A

Topology features

- Open Emitter configuration
- Temperature sensor
- Inverter
- Low side Kelvin Emitter for improved switching performance

Component features

- Easy paralleling
- Low turn-off losses
- Low collector emitter saturation voltage
- Positive temperature coefficient
- Short tail current
- Switching optimized for EMC

Housing features

- Base isolation: Al₂O₃
- Convex shaped substrate for superior thermal contact
- Compact housing
- CTI600 housing material
- Thermo-mechanical push-and-pull force relief
- Press-fit pin
- Reliable cold welding connection

Target applications

- Heat Pumps
- Servo Drives

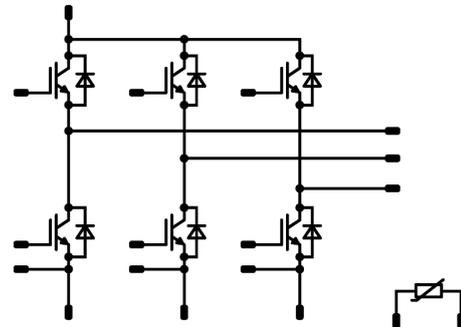
Types

- 10-EZ126PA050M702-L850F76T

flow E1 12 mm housing



Schematic





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Maximum Ratings

$T_j = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Inverter Switch				
Collector-emitter voltage	V_{CES}		1200	V
Collector current (DC current)	I_C	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	62	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	100	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	131	W
Gate-emitter voltage	V_{GES}		± 20	V
Short circuit ratings	i_{SC}	$V_{GE} = 15\text{ V}$, $V_{CC} = 800\text{ V}$ $T_j = 150\text{ °C}$	9,5	μs
Maximum junction temperature	T_{jmax}		175	$^{\circ}\text{C}$

Inverter Diode

Peak repetitive reverse voltage	V_{RRM}		1200	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	37	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	50	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	74	W
Maximum junction temperature	T_{jmax}		175	$^{\circ}\text{C}$

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^{\circ}\text{C}$
Operation temperature under switching condition	T_{jop}		-40...+($T_{jmax} - 25$)	$^{\circ}\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage $t_p = 2\text{ s}$	6000	V
Creepage distance			>12,7	mm
Clearance			8,62	mm
Comparative Tracking Index	CTI		≥ 600	



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Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		V_{GS} [V]	V_{GE} [V]	V_{DS} [V]	V_{CE} [V]	T_j [°C]	Min	Typ	Max	

Inverter Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$			10	0,005	25	5,4	6	6,6	V
Collector-emitter saturation voltage	$V_{CE(sat)}$		15		50	25 125 150		1,6 1,75 1,8	1,9	V
Collector-emitter cut-off current	I_{CES}		0	1200		25			0,09	mA
Gate-emitter leakage current	I_{GES}		20	0		25			0,5	μ A
Internal gate resistance	r_g							None		Ω
Input capacitance	C_{ies}							10000		pF
Output capacitance	C_{oes}		0	10		25		350		pF
Reverse transfer capacitance	C_{res}							130		pF
Gate charge	Q_g	$V_{CC} = 600$ V	0/15		50	25		380		nC

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						0,72		K/W
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10-EZ126PA050M702-L850F76T
target datasheet

Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		
Inverter Diode										
Static										
Forward voltage	V_F			25	25 125 150		1,6 1,7 1,7	2,1		V
Reverse leakage current	I_R	$V_r = 1200$ V			25			35		μA
Thermal										
Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)					1,28			K/W



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target datasheet

Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		V_{GS} [V]	V_{GE} [V]	V_{DS} [V]	V_F [V]	I_D [A]	I_F [A]	T_j [°C]	Min	

Thermistor

Static

Rated resistance	R					25		5		kΩ
Deviation of R100	$A_{R/R}$	$R_{100} = 499 \Omega$				100	3,2		3,3	%
Power dissipation	P					25		130		mW
Power dissipation constant	d					25		1,3		mW/K
B-value	$B_{(25/50)}$	Tol. $\pm 1 \%$						3380		K
Vincotech Thermistor Reference									V	



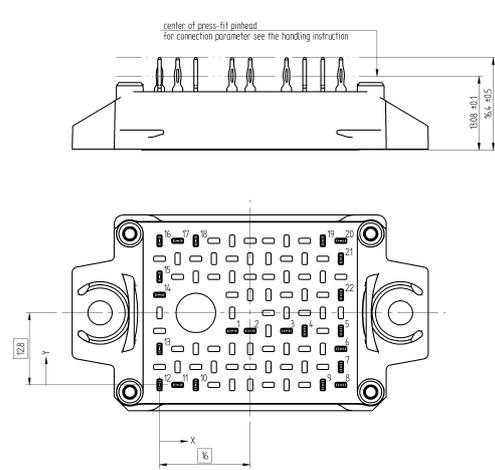
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target datasheet

Ordering Code	
Version	Ordering Code
Without thermal paste	10-EZ126PA050M702-L850F76T
With thermal paste (5,2 W/mK, PTM6000HV)	10-EZ126PA050M702-L850F76T-/-/7/

Marking						
	Text	Name NN-NNNNNNNNNNNNNN- TTTTTV	Date code WWYY	UL & VIN UL VIN	Lot LLLLL	Serial SSSS
	Datamatrix	Type&Ver TTTTTTTV	Lot number LLLLL	Serial SSSS	Date code WWYY	

Pin table [mm]				Outline
Pin	X	Y	Function	
1	12,8	9,6	DC+	
2	16	9,6	DC+	
3	22,4	9,6	Therm1	
4	25,6	9,6	Therm2	
5	32	9,6	DC-2	
6	32	6,4	S13	
7	32	3,2	DC-1	
8	32	0	S11	
9	28,8	0	G11	
10	6,4	0	Ph1	
11	3,2	0	Ph1	
12	0	0	G12	
13	0	6,4	G14	
14	0	16	Ph2	
15	0	19,2	Ph2	
16	0	25,6	G16	
17	3,2	25,6	Ph3	
18	6,4	25,6	Ph3	
19	28,8	25,6	G15	
20	32	25,6	S15	
21	32	22,4	DC-3	
22	32	16	G13	

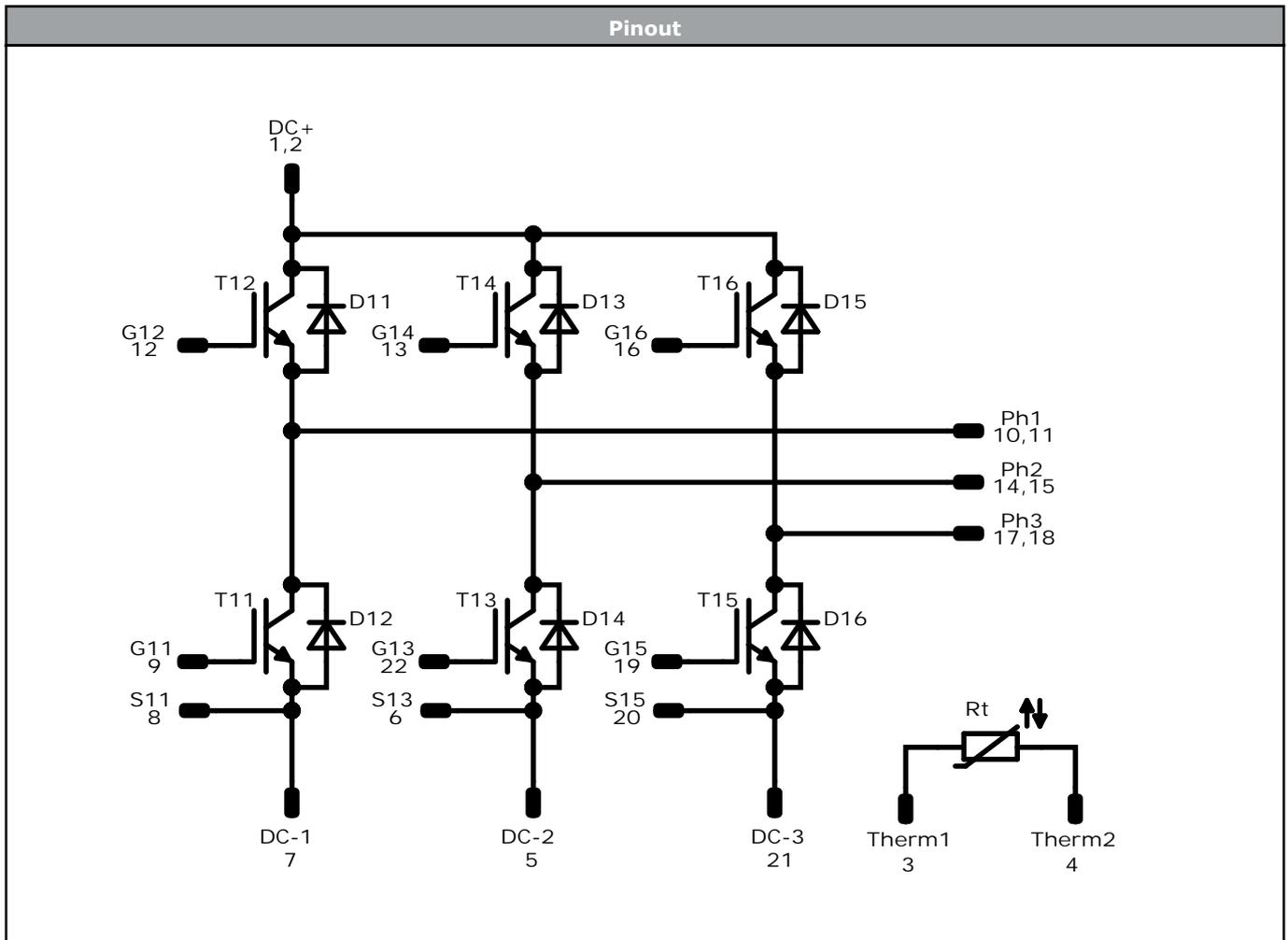


center of press-fit pinhead
for connection parameter see the handling instruction

Tolerance of pinpositions: ±0,4mm at the end of pins.
Dimension of coordinate axis is only official without tolerance



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Identification					
ID	Component	Voltage	Current	Function	Comment
T11, T12, T13, T14, T15, T16	IGBT	1200 V	50 A	Inverter Switch	
D11, D12, D13, D14, D15, D16	FWD	1200 V	25 A	Inverter Diode	
Rt	NTC			Thermistor	



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Packaging instruction				
Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ	Sample

Handling instruction
Handling instructions for <i>flow</i> E1 packages see vincotech.com website.

Package data
Package data for <i>flow</i> E1 packages see vincotech.com website.

Vincotech thermistor reference
See Vincotech thermistor reference table at vincotech.com website.

UL recognition and file number
This device is UL 1557 recognized under E192116 up to a junction temperature under switching condition $T_{j,op}=175^{\circ}\text{C}$ and up to 3500VAC/1min isolation voltage. For more information see vincotech.com website.



Document No.:	Date:	Modification:	Pages
10-EZ126PA050M702-L850F76T-T1-14	22 Jan. 2026	Initial Release	

Product status definition		
Datasheet Status	Product Status	Definition
Target	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice. The data contained is exclusively intended for technically trained staff.

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